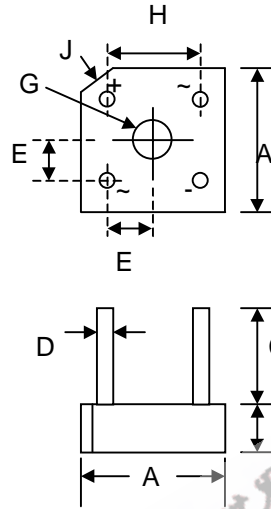


KBPC800G – KBPC810G

8.0A GLASS PASSIVATED BRIDGE RECTIFIER

Features

- Glass Passivated Die Construction
- High Current Capability
- High Case Dielectric Strength
- High Surge Current Capability
- Ideal for Printed Circuit Board Application
- Plastic Material has Underwriters Laboratory Flammability Classification 94V-O



KBPC-8		
Dim	Min	Max
A	18.54	19.56
B	6.35	7.60
C	19.00	—
D	1.27 Ø Typical	
E	5.33	7.37
G	Hole for #6 screw	
	3.60	4.00
H	12.20	13.20
J	2.38 x 45° Typical	
All Dimensions in mm		

Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Marked on Body
- Weight: 5.4 grams (approx.)
- Mounting Position: Through Hole for #6 Screw
- Mounting Torque: 5.0 Inch-pounds Maximum
- Marking: Type Number

Maximum Ratings and Electrical Characteristics @ $T_A=25^\circ\text{C}$ unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%.

Characteristic	Symbol	KBPC 800G	KBPC 801G	KBPC 802G	KBPC 804G	KBPC 806G	KBPC 808G	KBPC 810G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	V
Average Rectified Output Current (Note 1) @ $T_A = 50^\circ\text{C}$	I_O	8.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	160							A
Forward Voltage (per element) @ $I_F = 4.0\text{A}$	V_{FM}	1.1							V
Peak Reverse Current @ $T_C = 25^\circ\text{C}$ At Rated DC Blocking Voltage @ $T_C = 125^\circ\text{C}$	I_R	5.0 500							μA
I^2t Rating for Fusing ($t < 8.3\text{ms}$) (Note 2)	I^2t	160							A^2s
Typical Junction Capacitance (Note 3)	C_j	200							pF
Typical Thermal Resistance (Note 4)	$R_{\theta JC}$	6.0							K/W
Operating and Storage Temperature Range	T_j, T_{STG}	-55 to +150							$^\circ\text{C}$

- Note: 1. Mounted on 8.6" sq. x 0.24" thick Al. plate.
 2. Non-repetitive, for $t > 1\text{ms}$ and $< 8.3\text{ms}$.
 3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
 4. Thermal resistance junction to case per element.

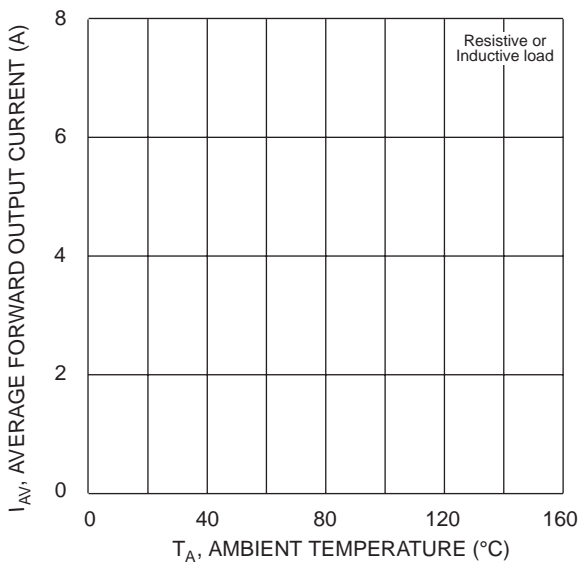


Fig. 1 Forward Current Derating Curve

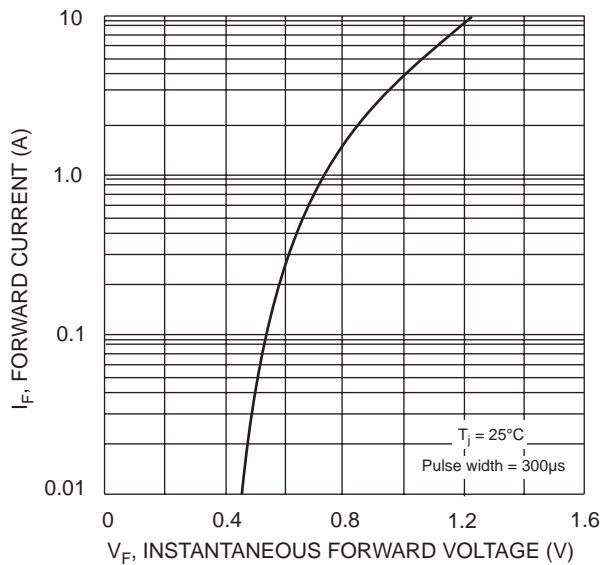


Fig. 2 Typical Forward Characteristics, per element

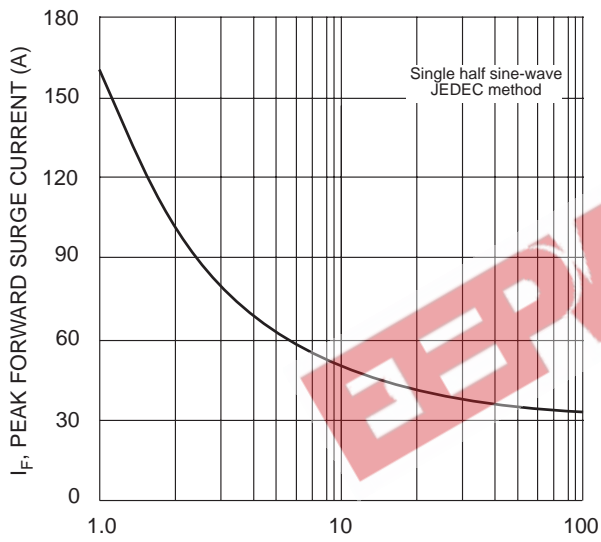


Fig. 3 Forward Surge Current

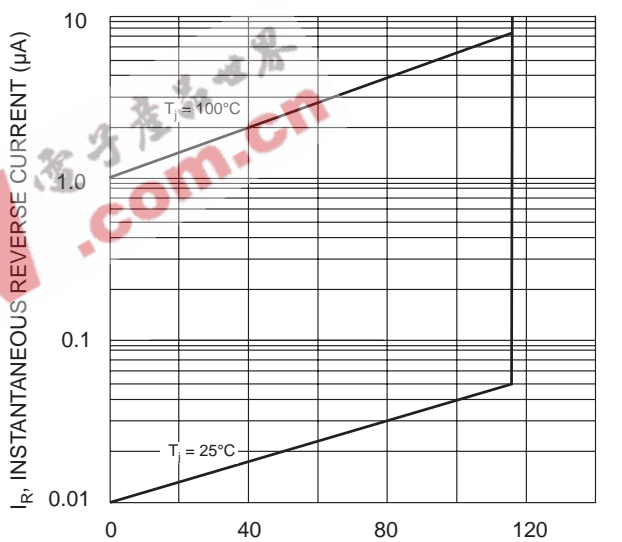


Fig. 4 Typical Reverse Characteristics, per element

ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
KBPC800G	Square Bridge	200 Units/Box
KBPC801G	Square Bridge	200 Units/Box
KBPC802G	Square Bridge	200 Units/Box
KBPC804G	Square Bridge	200 Units/Box
KBPC806G	Square Bridge	200 Units/Box
KBPC808G	Square Bridge	200 Units/Box
KBPC810G	Square Bridge	200 Units/Box

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

EEPW 电子產品世界
.com.cn

Won-Top Electronics Co., Ltd (WTE) has checked all information carefully and believes it to be correct and accurate. However, WTE cannot assume any responsibility for inaccuracies. Furthermore, this information does not give the purchaser of semiconductor devices any license under patent rights to manufacturer. WTE reserves the right to change any or all information herein without further notice.

WARNING: DO NOT USE IN LIFE SUPPORT EQUIPMENT. WTE power semiconductor products are not authorized for use as critical components in life support devices or systems without the express written approval.

Won-Top Electronics Co., Ltd.

No. 44 Yu Kang North 3rd Road, Chine Chen Dist., Kaohsiung, Taiwan

Phone: 886-7-822-5408 or 886-7-822-5410

Fax: 886-7-822-5417

Email: sales@wontop.com

Internet: <http://www.wontop.com>

We power your everyday.